



40V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(on)} Max	I _D T _A = +25°C
40)/	60mΩ @ V _{GS} = -10V	-6.4A
-40V	100mΩ @ V _{GS} = -4.5V	-5.0A

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(on)}) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- DC-DC converters
- Power management functions
- Backlighting

Features and Benefits

- Low Input Capacitance
- Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

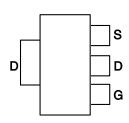
https://www.diodes.com/quality/product-definitions/

Mechanical Data

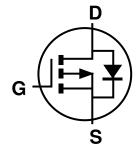
- Package: SOT223
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish @3
- Weight: 0.112 grams (Approximate)







Pin Out - Top



Equivalent Circuit

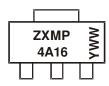
Ordering Information (Note 4)

	Part Number	Dockoro	Pac	acking	
		Package	Qty.	Carrier	
	ZXMP4A16GTA	SOT223 (Type DN)	1000	Tape & Reel	
	ZXMP4A16GTC	SOT223 (Type DN)	4000	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



ZXMP4A16 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 2 = 2022) WW or \overline{W} W = Week Code (01 to 53)



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V _{DSS}	-40	V
Gate-Source Voltage	Vgss	±20	V
Continuous Drain Current, V _{GS} = -10V	I _D	-6.4 -5.1 -4.6	А
Maximum Body Diode Forward Current (Note 5)	Is	-6.4	Α
Pulsed Drain Current (Note 7)	I _{DM}	-21	Α
Pulsed Source Current (Note 7)	lsм	-21	Α

Thermal Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Power Dissipation Linear Derating Factor	T _A = +25°C (Note 6)	P _D	2.0 16	W mW/°C
Total Power Dissipation Linear Derating Factor	T _A = +25°C (Note 5)	P _D	3.9 31	W mW/°C
The word Decistors of Lunction to Ambient	Steady State (Note 6)	Б	62.5	°C/W
Thermal Resistance, Junction to Ambient	Steady State (Note 5)	$R_{\theta JA}$	32	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	-40	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	-1.0	μΑ	V _{DS} = -40V, V _{GS} = 0V	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	$V_{GS(th)}$	-1.0	1	_	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
Static Drain-Source On-Resistance (Note 9)	Dear	_		60	mΩ	$V_{GS} = -10V$, $I_{D} = -3.8A$	
Static Drain-Source On-Nesistance (Note 9)	RDS(on)	_	ı	100	11122	V _{GS} = -4.5V, I _D = -2.9A	
Diode Forward Voltage (Note 9)	V _{SD}	_	-0.85	-1.2	V	$V_{GS} = 0V$, $I_S = -3.4A$	
Forward Transconductance (Notes 9 & 10)	g fs	_	8.85	_	S	$V_{DS} = -15V, I_D = -3.8A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	_	1,007	1		V _{DS} = -20V, V _{GS} = 0V f = 1.0MHz	
Output Capacitance	Coss	_	130	_	pF		
Reverse Transfer Capacitance	Crss	_	85	_			
Total Gate Charge (V _{GS} = -5.0V)	Qg	_	13.6	1		V _{DS} = -20V, I _D = -3.8A	
Total Gate Charge (V _{GS} = -10V)	Qg	_	26.1	_	nC		
Gate-Source Charge	Q _{gs}	_	2.8	_	IIC		
Gate-Drain Charge	Q_{gd}	_	4.8	_			
Turn-On Delay Time	tD(on)	_	2.33	_			
Turn-On Rise Time	tr	_	8.84	_	no	$\begin{aligned} V_{GS} &= \text{-}10\text{V}, \ V_{DD} = \text{-}20\text{V}, \ R_G = 6.0\Omega \\ I_D &= \text{-}1.0\text{A} \end{aligned}$	
Turn-Off Delay Time	tD(off)	_	29.18	_	ns		
Turn-Off Fall Time	tf	_	12.54	_			
Body Diode Reverse Recovery Time	trr	_	27.2	_	ns	I= 24 dl/dt 1004/up	
Body Diode Reverse Recovery Charge	Qrr	_	25.4	_	nC	IF = -3A, dI/dt = 100A/μs	

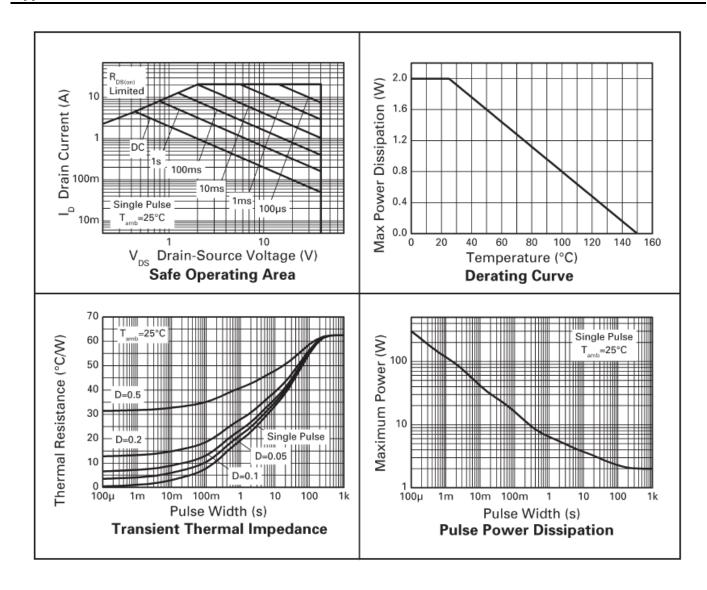
5. For a device surface mounted on FR4 PCB measured at $t \le 10s$. Notes:

- 6. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

 7. Repetitive rating 25mm x 25mm FR4 PCB, D = 0.05, pulse width limited by maximum junction temperature.
- 8. Short duration pulse test used to minimize self-heating effect.
- 9. Measured under pulsed conditions. Width ≤ 300µs. Duty cycle ≤ 2%.
- 10. Guaranteed by design. Not subject to product testing.

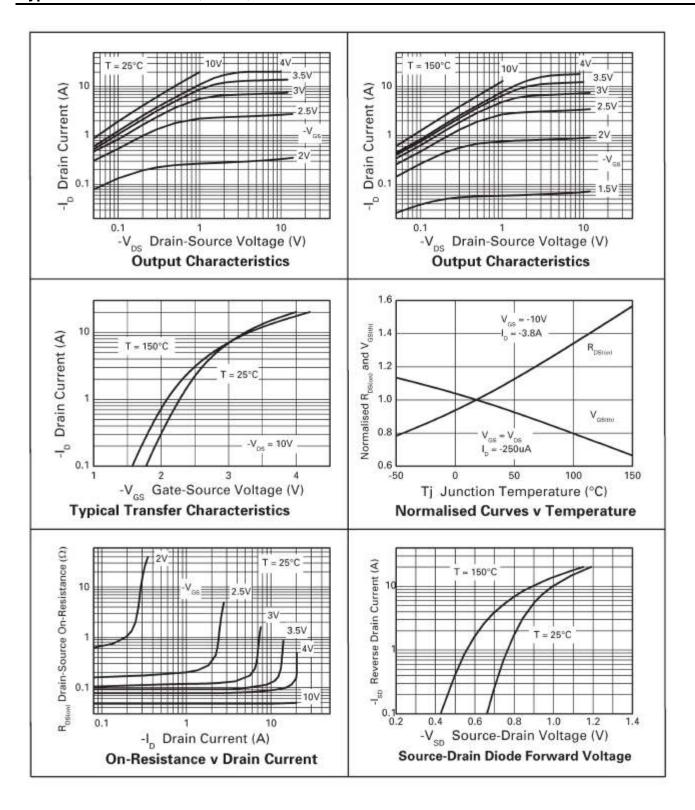


Typical Characteristics



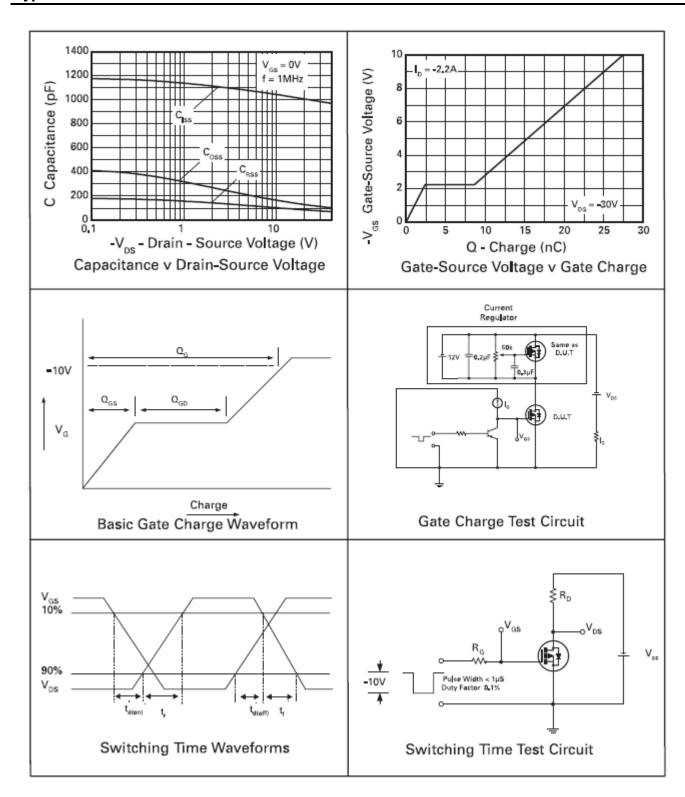


Typical Characteristics (continued)





Typical Characteristics (continued)

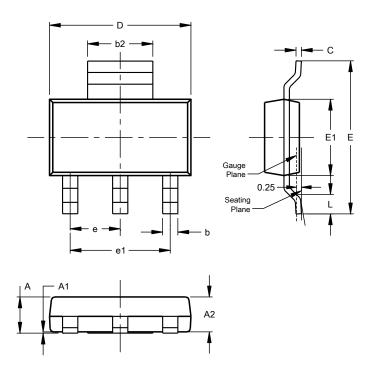




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

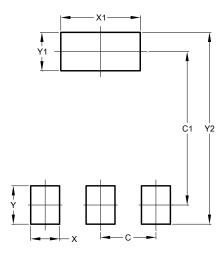


SOT223 (Type DN)				
Dim	Min	Max	Тур	
Α		1.70		
A1	0.01	0.15		
A2	1.50	1.68	1.60	
b	0.60	0.80	0.70	
b2	2.90	3.10		
С	0.20	0.32		
D	6.30	6.70		
Е	6.70	7.30		
E1	3.30	3.70		
е			2.30	
e1			4.60	
L	0.85			
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00



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